

Product Information Sheet

EPO-TEK® TH106-6

Date: September 2017 Recommended Cure: 150°C / 1 Hour

Rev: III
No. of Components: Single
Mix Ratio by Weight: N/A
Specific Gravity: 1.75
Pot Life: 28 Days

Shelf Life- Bulk: One year at -40°C

NOTES:

• Container(s) should be kept closed when not in use.

• Filled systems should be stirred thoroughly before mixing and prior to use.

• Performance properties (rheology, conductivity, others) of the product may vary from those stated on the data sheet when bi-pak/syringe packaging or post-processing of any kind is performed. Epoxy's warranties shall not apply to any products that have been reprocessed or repackaged from Epoxy's delivered status/container into any other containers of any kind, including but not limited to syringes, bi-paks, cartridges, pouches, tubes, capsules, films or other packages.

<u>Product Description:</u> A single component, thermally conductive epoxy for semiconductor and microelectronic assembly. It is designed for superior wetting and adhesion strength to gold hybrid circuit substrates and packaging materials. It is a replacement for EPO-TEK® TH106.

<u>Typical Properties:</u> Cure condition: 150°C / 1 Hour Different batches, conditions & applications yield differing results.

Data below is not guaranteed. To be used as a guide only, not as a specification. * denotes test on lot acceptance basis

PHYSICAL PROPERTIES:				
* Color (before cure):		White		
* Consistency:		Smooth paste		
* Viscosity (23°C) @ 10 rpm:		25,000-35,000	cPs	
Thixotropic Index:		4.6		
* Glass Transition Temp:		≥ 90	°C (Dynamic Cure: 20-200°C/ISO 25 Min; Ramp -10-200°C @20°C/Min)	
Coefficient of Thermal Expansion (CTE):				
	Below Tg:	50	x 10 ⁻⁶ in/in°C	
	Above Tg:	129	x 10 ⁻⁶ in/in°C	
Shore D Hardness:		67		
Lap Shear @ 23°C:		> 2,000	psi	
Die Shear @ 23°C:		≥ 25	Kg 8,890 psi	
Degradation Temp:		367	°C	
Weight Loss:				
	@ 200°C:	0.16	%	
	@ 250°C:	0.60	%	
	@ 300°C:	1.13	%	
Suggested Operating Temperature:		< 300	°C (Intermittent)	
Storage Modulus:		981,347	psi	
* Particle Size:		≤ 20	microns	

ELECTRICAL AND THERMAL PROPERTIES	3:	
Thermal Conductivity:	0.8	W/mK
Volume Resistivity @ 23°C:	$\geq 1 \times 10^{13}$	Ohm-cm
Dielectric Constant (1KHz):	4.35	
Dissipation Factor (1KHz):	0.003	